

# NOT RECOMMENDED FOR NEW DESIGN CONTACT US



SBRT3M60SA

# 3A TrenchSBR TRENCH SUPER BARRIER RECTIFIER

#### **Product Summary**

| VRRM (V) | Io (A) | V <sub>F(MAX)</sub> (V)<br>@ +25°C | I <sub>R(MAX)</sub> (mA)<br>@ +25°C |
|----------|--------|------------------------------------|-------------------------------------|
| 60       | 3      | 0.59                               | 0.1                                 |

#### **Description and Applications**

The SBRT3M60SA is a 3A 60V single rectifier packaged in the low profile SMA package. Providing low  $V_{\text{F}}$  and excellent reverse leakage stability at high temperatures, this device is ideal for use in general rectification applications such as:

- Boost Diode
- Blocking Diode
- Recirculating Diode

#### **Features and Benefits**

- Reduced reverse leakage (I<sub>R</sub>) and low forward voltage drop (V<sub>F</sub>);
  better efficiency and cooler operation.
- Reduced high temperature reverse leakage; Increased reliability against thermal runaway failure in high temperature operation.
- Patented TrenchSBR<sup>®</sup> Technology
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: SMA
- Case Material: Molded Plastic, "Green" Molding Compound;
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Polarity: Cathode Band
- Weight: 0.064 grams (Approximate)







**SMA** 

**Bottom View** 



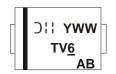
#### Ordering Information (Note 4)

| =  |               |      |                   |
|----|---------------|------|-------------------|
| ╓  | Part Number   | Case | Packaging         |
| Iſ | SBRT3M60SA-13 | SMA  | 5.000/Tape & Reel |

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  - 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



TV6 = Product Type Marking Code YWW = Date Code Marking Y = Last Digit of Year (ex: 1 for 2021) WW = Week Code (01 to 53) AB = Foundry and Assembly Code



#### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic  | Symbol              | Value | Unit |
|---|---------------------|-------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage              | VRRM<br>VRWM<br>VRM | 60    | V    |
| Average Rectified Output Current  | lo                  | 3     | Α    |
| Non-Repetitive Peak Forward Surge Current 8.3ms<br>Single Half Sine-Wave Superimposed on Rated Load | IFSM                | 50    | А    |

#### **Thermal Characteristics**

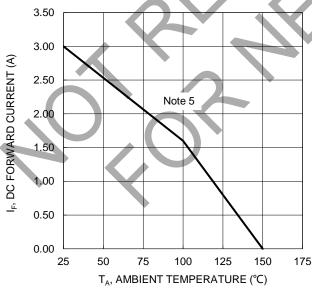
| Characteristic  | Symbol            | Value       | Unit |
|---|-------------------|-------------|------|
| Typical Thermal Resistance Junction to Ambient (Note 5) | R <sub>0</sub> JA | 90          | °C/W |
| Typical Thermal Resistance Junction to Case (Note 5)    | Rejc              | 33          | °C/W |
| Operating and Storage Temperature Range                 | TJ, TSTG          | -55 to +150 | °C   |

#### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

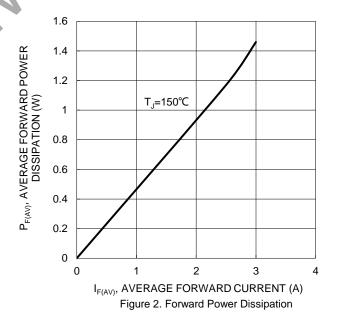
| Characteristic           | Symbol | Min | Тур | Max          | Unit | Test Condition  |
|--------------------------|--------|-----|-----|--------------|------|---|
| Forward Voltage Drop     | VF     | 41  | _   | 0.59<br>0.57 | V    | I <sub>F</sub> = 3A, T <sub>J</sub> = +25°C<br>I <sub>F</sub> = 3A, T <sub>J</sub> = +125°C |
| Leakage Current (Note 6) | IR     | 7   | _   | 0.1<br>10    | mA   | $V_R = 60V, T_J = +25$ °C<br>$V_R = 60V, T_J = +125$ °C                                     |

Notes:

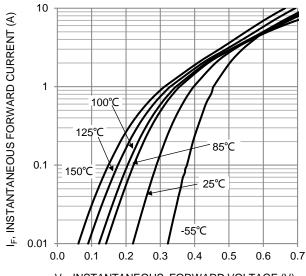
- $5. \ \, \text{Device mounted on FR-4 substrate, } 0.4"*0.5", 20z, single-sided, PC \ boards \ with } 0.2"*0.25" \ copper \ pad. \\$
- 6. Short duration pulse test used to minimize self-heating effect.



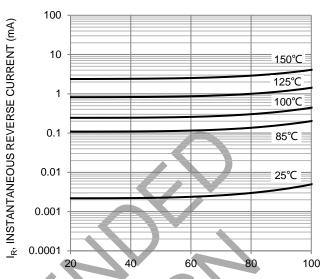




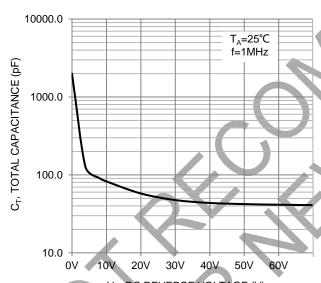




 $V_{\text{F}}$ , INSTANTANEOUS FORWARD VOLTAGE (V) Figure 3. Typical Forward Characteristics



V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (%) Figure 4. Typical Reverse Characteristics



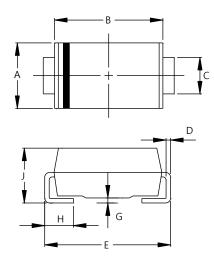
V<sub>R</sub>, DC REVERSE VOLTAGE (V) Figure 5. Total Capacitance vs. Reverse Voltage



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SMA

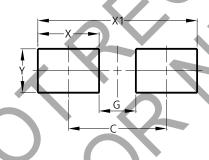


| SMA                  |      |      |  |  |
|----------------------|------|------|--|--|
| Dim                  | Min  | Max  |  |  |
| Α                    | 2.29 | 2.92 |  |  |
| В                    | 4.00 | 4.60 |  |  |
| С                    | 1.27 | 1.63 |  |  |
| D                    | 0.15 | 0.31 |  |  |
| E                    | 4.80 | 5.59 |  |  |
| G                    | 0.05 | 0.20 |  |  |
| 7                    | 0.76 | 1.52 |  |  |
| 7                    | 1.96 | 2.40 |  |  |
| All Dimensions in mm |      |      |  |  |

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SMA



| Dimensions | Value<br>(in mm) |
|------------|------------------|
| С          | 4.00             |
| G          | 1.50             |
| Х          | 2.50             |
| X1         | 6.50             |
| V          | 1.70             |



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